TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC74LCX244F,TC74LCX244FW,TC74LCX244FT

#### Low-Voltage Octal Bus Buffer with 5-V Tolerant Inputs and Outputs

The TC74LCX244F/FW/FT is a high-performance CMOS octal bus buffer. Designed for use in 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

The device is designed for low-voltage (3.3 V) VCC applications, but it could be used to interface to 5 V supply environment for both inputs and outputs.

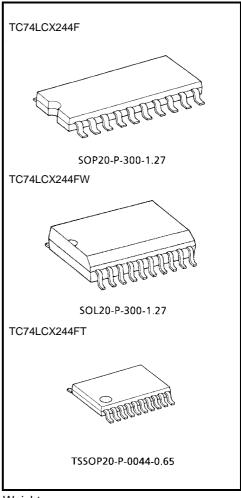
The 74LCX244F/FW/FT is a non-inverting 3-state buffer having two active-low output enables. This device is designed to be used with 3-state memory address drivers, etc.

All inputs are equipped with protection circuits against static discharge.

#### **Features**

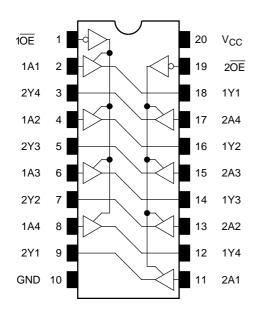
- Low-voltage operation:  $V_{CC} = 2.0$  to 3.6 V
- High-speed operation:  $t_{pd} = 6.5 \text{ ns (max) (VCC} = 3.0 \text{ to } 3.6 \text{ V)}$
- Ouput current:  $|I_{OH}|/I_{OL} = 24 \text{ mA (min)} (V_{CC} = 3.0 \text{ V})$
- Latch-up performance: ±500 mA
- Available in JEDEC SOP, JEITA SOP and TSSOP
- Power-down protection provided on all inputs and outputs
- Pin and function compatible with the 74 series (74AC/VHC/HC/F/ALS/LS etc.) 244 type

Note: xxxFW (JEDEC SOP) is not available in Japan.

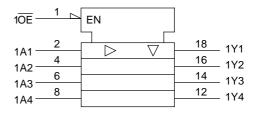


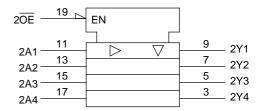
Weight SOP20-P-300-1.27: 0.22 g (typ.) SOL20-P-300-1.27: 0.46 g (typ.) TSSOP20-P-0044-0.65: 0.08 g (typ.)

### Pin Assignment (top view)



## **IEC Logic Symbol**





### **Truth Table**

Inp	uts	Outputs
ŌE	An	Outputs
L	L	L
L	Н	Н
Н	Х	Z

X: Don't care

Z: High impedance

## **Maximum Ratings**

Characteristics	Symbol	Rating	Unit
Power supply voltage	V <sub>CC</sub>	-0.5 to 7.0	V
DC input voltage	V <sub>IN</sub>	-0.5 to 7.0	V
		-0.5 to 7.0 (Note 1)	
DC output voltage	V <sub>OUT</sub>	-0.5 to V <sub>CC</sub> + 0.5	V
		(Note 2)	
Input diode current	I <sub>IK</sub>	-50	mA
Output diode current	I <sub>OK</sub>	±50 (Note 3)	mA
DC output current	I <sub>OUT</sub>	±50	mA
Power dissipation	P <sub>D</sub>	180	mW
DC V <sub>CC</sub> /ground current	I <sub>CC</sub> /I <sub>GND</sub>	±100	mA
Storage temperature	T <sub>stg</sub>	-65 to 150	

Note 1: Output in OFF state

Note 2: High or low state. IOUT absolute maximum rating must be observed.

Note 3: V<sub>OUT</sub> < GND, V<sub>OUT</sub> > V<sub>CC</sub>



# **Recommended Operating Conditions**

Characteristics	Symbol	Rating	Unit	
Power supply voltage	V <sub>CC</sub>	2.0 to 3.6	V	
Power supply voltage	vcc vcc	1.5 to 3.6 (Note 4)	V	
Input voltage	V <sub>IN</sub>	0 to 5.5	V	
Output voltage	Vout	0 to 5.5 (Note 5)	V	
Output voltage	VOUT	0 to V <sub>CC</sub> (Note 6)	V	
Output ourropt	la/la.	±24 (Note 7)	mA	
Output current	I <sub>OH</sub> /I <sub>OL</sub>	±12 (Note 8)	IIIA	
Operating temperature	T <sub>opr</sub>	-40 to 85	°C	
Input rise and fall time	dt/dv	0 to 10 (Note 9)	ns/V	

Note 4: Data retention only

Note 5: Output in OFF state

Note 6: High or low state

Note 7:  $V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$ 

Note 8:  $V_{CC} = 2.7 \text{ to } 3.0 \text{ V}$ 

Note 9:  $V_{IN} = 0.8 \text{ to } 2.0 \text{ V}, V_{CC} = 3.0 \text{ V}$ 

#### **Electrical Characteristics**

# DC Characteristics ( $Ta = -40 \text{ to } 85^{\circ}\text{C}$ )

Characteristics		Symbol	Symbol Test Condition			Min	Max	Unit		
Onaracionsi	103	Oymbor	rest condition		V <sub>CC</sub> (V)	IVIIII	IVIAX	Offic		
Input voltage	H-level	VIH	_	_	2.7 to 3.6	2.0	_	V		
input voltage	L-level	V <sub>IL</sub>	_	_	2.7 to 3.6	_	0.8	v		
				I <sub>OH</sub> = -100 μA	2.7 to 3.6	V <sub>CC</sub> - 0.2				
	H-level	Voh	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -12 mA	2.7	2.2	_			
				$I_{OH} = -18 \text{ mA}$	3.0	2.4	_			
Output voltage				I <sub>OH</sub> = -24 mA	3.0	2.2	_	V		
		\/	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OL} = 100  \mu\text{A}$ $I_{OL} = 12 \text{ mA}$ $I_{OL} = 16 \text{ mA}$ $I_{OL} = 24 \text{ mA}$	I <sub>OL</sub> = 100 μA	2.7 to 3.6	_	0.2			
	L-level			I <sub>OL</sub> = 12 mA	2.7	_	0.4			
	L-level	V <sub>OL</sub>		VIN — VIH OI VIL	$I_{OL} = 16$	I <sub>OL</sub> = 16 mA	3.0	_	0.4	
				I <sub>OL</sub> = 24 mA	3.0	_	0.55			
Input leakage current		I <sub>IN</sub>	V <sub>IN</sub> = 0 to 5.5 V		2.7 to 3.6	_	±5.0	μΑ		
3-state output off-state	current	l <sub>OZ</sub>	$V_{IN} = V_{IH}$ or $V_{IL}$	$V_{IN} = V_{IH}$ or $V_{IL}$		_	±5.0	μА		
		102	V <sub>OUT</sub> = 0 to 5.5 V		$I_{OZ}$ $V_{OUT} = 0 \text{ to } 5.5 \text{ V}$ 2.7 to					P
Power off leakage curr	rent	l <sub>OFF</sub>	$V_{IN}/V_{OUT} = 5.5 \text{ V}$		0	_	10.0	μΑ		
Quiescent supply curre	ant	$I_{CC}$ $V_{IN} = V_{CC}$ or GND			2.7 to 3.6	_	10.0			
Quioscont supply cult		100	V <sub>IN</sub> /V <sub>OUT</sub> = 3.6 to 5.5 V		2.7 to 3.6	_	±10.0	μΑ		
Increase in I <sub>CC</sub> per inp	out	Δlcc	$V_{IH} = V_{CC} - 0.6$		2.7 to 3.6	_	500			

3



### AC Characteristics ( $Ta = -40 \text{ to } 85^{\circ}\text{C}$ )

Characteristics	Characteristics Symbol Test Condition			Min	Max	Unit
	- J		V <sub>CC</sub> (V)			
Propagation delay time	t <sub>pLH</sub>	Figure 1, Figure 2	2.7	_	7.5	ns
1 Topagation dolay time	t <sub>pHL</sub>	1 19410 1, 1 19410 2	$3.3 \pm 0.3$	1.5	6.5	113
Output enable time	t <sub>pZL</sub>	Figure 1, Figure 3	2.7		9.0	ns
Output enable time	t <sub>pZH</sub>	rigule 1, rigule 3	$3.3 \pm 0.3$	1.5	8.0	
Output disable time	t <sub>pLZ</sub>	Figure 1, Figure 3	2.7		8.0	ns
Output disable time	t <sub>pHZ</sub>	Trigule 1, Figure 3	$3.3 \pm 0.3$	1.5	7.0	2
Output to output skew	t <sub>osLH</sub>	(Note 10)	2.7	_		ns
Output to output skew	t <sub>osHL</sub>	(Note 10)	$3.3 \pm 0.3$	_	1.0	

Note 10: Parameter guaranteed by design.

 $(t_{OSLH} = |t_{PLHm} - t_{PLHn}|, t_{OSHL} = |t_{PHLm} - t_{PHLn}|)$ 

## **Dynamic Switching Characteristics**

(Ta = 25°C, input:  $t_r = t_f = 2.5 \text{ ns}$ ,  $C_L = 50 \text{ pF}$ ,  $R_L = 500 \Omega$ )

Characteristics		Symbol	Test Condition	V <sub>CC</sub> (V)	Тур.	Unit
Quiet output maximum dynamic	V <sub>OL</sub>	V <sub>OLP</sub>	$V_{IH}=3.3\;V,V_{IL}=0\;V$	3.3	0.8	V
Quiet output minimum dynamic	V <sub>OL</sub>	V <sub>OLV</sub>	$V_{IH}=3.3~V,~V_{IL}=0~V$	3.3	0.8	V

## **Capacitive Characteristics (Ta = 25°C)**

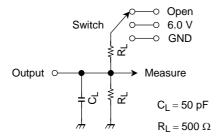
Characteristics	Symbol	Test Condition		V <sub>CC</sub> (V)	Тур.	Unit
Input capacitance	C <sub>IN</sub>	_		3.3	7	pF
Output capacitance	C <sub>OUT</sub>	_		3.3	8	pF
Power dissipation capacitance	C <sub>PD</sub>	f <sub>IN</sub> = 10 MHz	(Note 11)	3.3	25	pF

Note 11: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8 \text{ (per bit)}$ 

#### **AC Test Circuit**



Parameter	Switch		
t <sub>pLH</sub> , t <sub>pHL</sub>	Open		
t <sub>pLZ</sub> , t <sub>pZL</sub>	6.0 V		
t <sub>pHZ</sub> , t <sub>pZH</sub>	GND		

Figure 1

#### **AC Waveform**

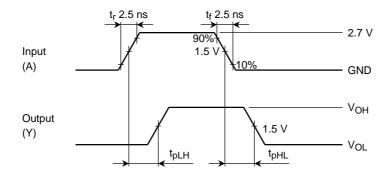
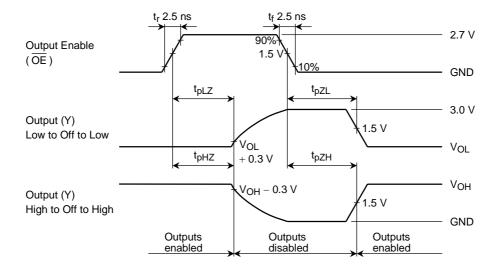


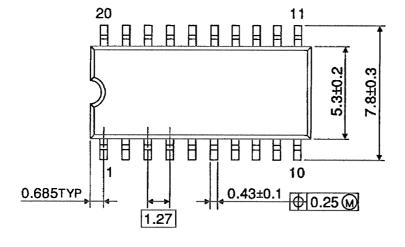
Figure 2 t<sub>pLH</sub>, t<sub>pHL</sub>

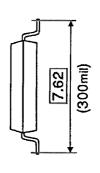


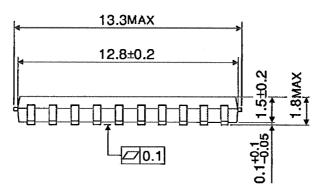
 $\textbf{Figure 3} \quad t_{\text{pLZ}},\, t_{\text{pHZ}},\, t_{\text{pZL}},\, t_{\text{pZH}}$ 

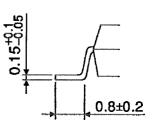
# **Package Dimensions**

SOP20-P-300-1.27 Unit: mm







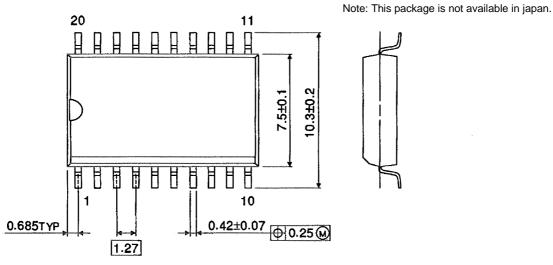


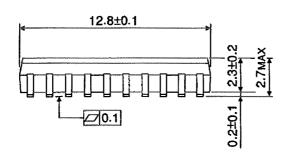
Weight: 0.22 g (typ.)

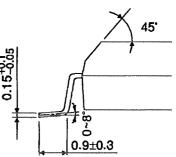
# **Package Dimensions**

SOL20-P-300-1.27

Unit: mm





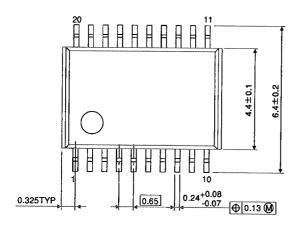


Weight: 0.46 g (typ.)

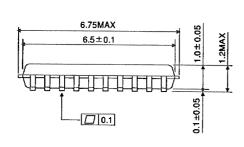
Unit: mm

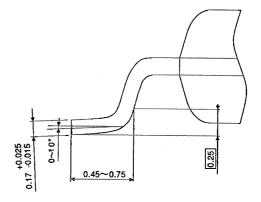
# **Package Dimensions**

TSSOP20-P-0044-0.65









Weight: 0.08 g (typ.)

#### **RESTRICTIONS ON PRODUCT USE**

000707EBA

- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.
  In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.
- The products described in this document are subject to the foreign exchange and foreign trade laws.
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any intellectual property or other rights of TOSHIBA CORPORATION or others.
- The information contained herein is subject to change without notice.